

View Online at <https://aerobasegroup.com/nsn/5961-00-526-7975>

Inclosure Material:

Glass all semiconductor device diode

Overall Length:

0.265 inches 2nd semiconductor device diode

Terminal Length:

1.000 inches 3rd semiconductor device diode

Overall Diameter:

0.096 inches 3rd semiconductor device diode

Internal Configuration:

Junction contact all semiconductor device diode

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

Do-35 1st semiconductor device diode

Internal Junction Configuration:

Pn all semiconductor device diode

Component Function Relationship:

Unmatched

Component Name And Quantity:

3 semiconductor device diode

Mounting Method:

Terminal all semiconductor device diode

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon all semiconductor device diode

Voltage Rating In Volts Per Characteristic:

20.0 working peak reverse voltage, peak total value 3rd semiconductor device diode

Current Rating Per Characteristic:

450.00 milliamperes source cutoff current outside diameter 1st semiconductor device diode

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector preset 3rd semiconductor device diode

Maximum Operating Temperature Per Measurement Point:

150.0 degrees celsius ambient air all semiconductor device diode

Terminal Type And Quantity:

2 uninsulated wire lead all semiconductor device diode

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

Fig:

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